Contents L6377

Contents

1	Pin con	nnections	5
2	Maximu	um ratings	6
3	Electric	cal characteristics	7
	3.1	Schematic diagram	9
	3.2	Input section	10
	3.3	Overtemperature protection	10
	3.4	Undervoltage protection	10
4	Overcu	rrent operation	11
5	Demagi	netization of inductive loads	13
6	Packag	e information	15
	6.1	SO-14L package information	15
7	Revisio	on history	18



L6377 List of tables

List of tables

Table 1: Device summary	1
Table 2: Pin description	5
Table 3: Absolute maximum ratings	
Table 4: Thermal data	
Table 5: Electrical characteristics	
Table 6: SO-14L package mechanical data	
Table 7: Document revision history	



List of figures L6377

List of figures

Figure 1: Pin connections (top view)	5
Figure 2: Block diagram	
Figure 3: Undervoltage comparator hysteresis	
Figure 4: Switching waveforms	
Figure 5: Short-circuit operation waveforms	
Figure 6: Input comparator hysteresis	
Figure 7: External demagnetisation circuit (versus ground)	13
Figure 8: External demagnetisation circuit	14
Figure 9: SO-14L package outline	15
Figure 10: SO-14L recommended footprint outline	



L6377 Pin connections

1 Pin connections

Figure 1: Pin connections (top view)

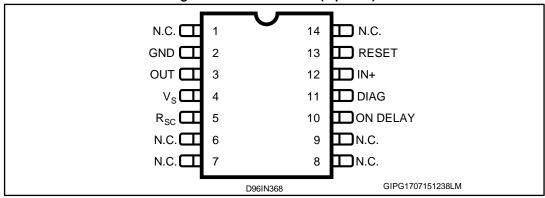


Table 2: Pin description

Pin	Pin name	Function
1, 6, 7, 8, 9, 14	N.C.	Not connected
2	GND	Ground pin
3	OUT	High-side output. Controlled output with current limitation
4	Vs	Supply voltage. Range with undervoltage monitoring
5	R _{SC}	Current limiting setting
10	ON DELAY	Delay setting for overcurrent diagnostic
11	DIAG	Diagnostic open drain output for overtemperature, undervoltage and overcurrent
12	IN+	Comparator non-inverting input
13	RESET	Asynchronous reset input

Maximum ratings L6377

2 Maximum ratings

Table 3: Absolute maximum ratings

Symbol	Parameter	Value	Unit
V	Pin 4: supply voltage (tw ≤ 10 ms)	50	V
Vs	Pin 4: supply voltage (DC)	40	V
V _S - V _{OUT}	Pin 4 vs 3: supply to output differential voltage	Internally limited	V
V_{od}	Pin 10: externally forced voltage	-0.3 to 7	V
I _{od}	Pin 10: externally forced current	± 1	mA
I _{RESET}	Pin 13: reset input current (forced)	± 2	mA
V _{RESET}	Pin 13: reset input voltage	-0.3 to 40	V
l _{out}	Pin 3: output current	Internally limited	
V_{out}	Pin 3: output voltage	Internally limited	W
Eil	E _{il} Total energy inductive load: (T _J = 50		mJ
P _{tot}	P _{tot} Power dissipation Internally limited		
V _{diag}	Pin 11: external voltage	-0.3 to 40	V
l _{diag}	Pin 11: externally forced current	-10 to 10	mA
l _i	Pin 12: input current	20	mA
Vi	Pin 12: input voltage	-10 to V _s +0.3	V
T _{op} Ambient temperature, operating range -25		-25 to 85	°C
TJ	Junction tmperature, operating range	-25 to 125	°C
T _{stg}	Storage temperature	-55 to 150	°C

Table 4: Thermal data

Symbol	Parameter	Value	Unit
$R_{\text{th(JA)}}$	Thermal resistance junction-ambient	150 max.	°C/W

L6377 Electrical characteristics

3 Electrical characteristics

 $V_S = 24 \text{ V}$; $T_J = -25 \text{ to } 125 \,^{\circ}\text{C}$, unless otherwise specified

Table 5: Electrical characteristics

Symbol	Pin	Parameter	Test conditions	Min.	Тур.	Max.	Unit
DC opera	ition						
V_{smin}		Supply voltage for valid diagnostic	$I_{diag} \ge 0.5 \text{ mA};$ $V_{diag} = 1.5 \text{ V};$	4		35	V
Vs		Operative supply voltage		8	24	35	٧
V_{sth}	4	Undervoltage lower treshold		7		8	>
V_{shys}		Undervolatge hysteresis		300	500	700	mV
Iq		Quiocoont ourrant	Output pen		800		μΑ
I _{qo}		Quiescent current	Output on		1.6		mA
V_{ith}		Input threshold voltage		0.8	1.3	2	V
V _{iths}		Input threshold hysteresis		50		400	mV
Vil	12	Input low level voltage		-7		0.8	V
\/	12	Input high lovel veltage	V _S < 18 V	2		V _S -3	V
V_{ih}		Input high level voltage	V _S >18 V	2		15	V
I_{ib}		Input bias current	$V_i = -7 \text{ to } 15 \text{ V}$	-250		250	μΑ
V_{rth}		Reset threshold voltage		0.8	1.3	2	V
V_{rl}	40	Reset low level voltage		0		0.8	V
V_{rh}	13	Reset high level voltage		2		40	V
I _{rb}		Reset pull down current			5		μA
I _{dch}	10	Delay capacitor charging current	ON delay pin shorted-to-ground		2.5		μΑ
V _{rsc}		Output voltage on R _{SC} pin	R _{sc} pin floating		1.25		V
I _{rsc}	5	Output current on R _{SC} pin	R _{sc} pin shorted-to-GND			300	μA
I _{dlkg}	44	Diagnostic output leakage current	Diagnostic off			25	μΑ
V _{diag}	11	Diagnostic output voltage drop	I _{diag} = 5 mA			1.5	V
V		Output voltage drop	I _{out} = 625 mA T _J = 25 °C		250	350	mV
V_{don}		Output voltage drop	I _{out} = 625 mA T _J = 125 °C		400	500	1117
l _{olk}	3	Output leakage current	V _i = Iow; V _{out} = 0			100	μΑ
V _{ol}		Output low-state voltage	V _i = high; pin floating		0.8	1.5	V
V_{cl}		Internal voltage clamp (V _s - V _{out})	I _o = 200 mA single pulsed = 300 ms	48	53	58	٧



DocID1637 Rev 5 7/19

Symbol	Pin	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
I _{SC}		Short-circuit output current	$V_s = 8 \text{ to } 35 \text{ V};$ $R_l = 2 \Omega; R_{sc} = 5$ to 30 k \Omega	$5/R_{SC} = k\Omega$		А		
T _{max} .		Overtemperature upper threshold			150		°C	
T _{hys}		Overtemperature hysteresis			20		°C	
AC opera	ition		•					
t _r - t _f		Rise or fall time	$V_s = 24 \text{ V}; R_l = 70$ $\Omega R_l \text{ to ground}$		20		μs	
t _d	3	Delay time			5		·	
dV/dt		Slew rate (rise and fall edge)	$V_s = 24 \text{ V}; R_i = 70$ $\Omega R_i \text{ to ground}$	0.7	1	1.5	V/µs	
t _{ON}		On-time during short- circuit condition	50 pF < C _{DON} < 2 nF		1.28		μs/pF	
t _{OFF}	10	Off-time during short- circuit condition			64		t _{ON}	
f _{max.}		Maximum operating frequency			25		kHz	
Source d	Source drain NDMOS diode							
V _{fsd}		Forward on voltage	I _{fsd} = 625 mA		1	1.5	V	
I _{fp}		Forward peak current	t _p = 10 ms; duty cycle = 20%			1.5	Α	
t _{rr}		Reverse recovery time	I_{fsd} = 500 mA; dI_{fsd}/dt = 25 A/ μ s		200		ns	
t _{fr}		Forward recovery time			50		ns	

L6377 Electrical characteristics

3.1 Schematic diagram

Figure 2: Block diagram

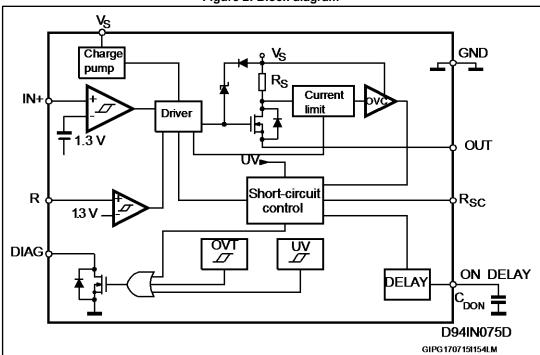
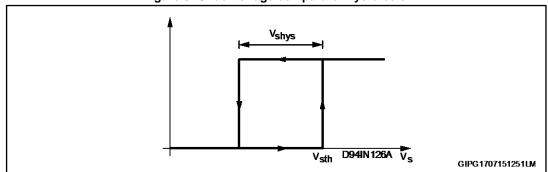


Figure 3: Undervoltage comparator hysteresis



Electrical characteristics L6377

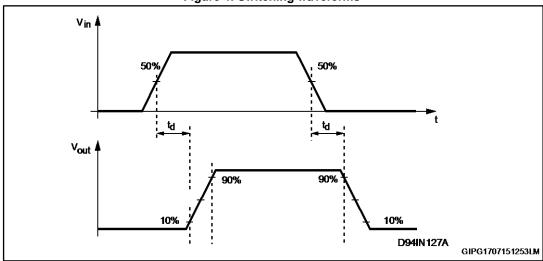


Figure 4: Switching waveforms

3.2 Input section

An input and asynchronous reset, TTL/CMOS compatible with wide voltage range and high noise immunity (thanks to a built-in hysteresis) is available.

3.3 Overtemperature protection

An on-chip overtemperature protection provides an excellent protection of the device in extreme conditions. Whenever the temperature, measured on a central portion of the chip, exceeds $T_{max.} = 150$ °C (typical value) the device shuts down, and the DIAG output goes low. Normal operation is resumed as the chip temperature (normally after few seconds) falls below $T_{max.}$ - $T_{hys} = 130$ °C (typical value). The hysteresis avoids that an intermittent behavior occurs.

3.4 Undervoltage protection

The supply voltage operates correctly in a range from 8 to 35 V. Below 8 V the overall system has to be considered not reliable. To avoid any misfunctioning, the supply voltage is continuously monitored to provide an undervoltage protection. As V_s falls below V_{sth} - V_{shys} (typically 7.5 V, see *Figure 4: "Switching waveforms"*) the output power MOSFET switches off and DIAG output goes low. Normal operation is resumed as soon as V_s exceeds V_{sth} . The hysteretic behaviour prevents intermittent operation at low supply voltage.



4 Overcurrent operation

In order to implement a short-circuit protection, the output power MOSFET is driven to linear mode to limit the output current to the I_{SC} value. This I_{SC} limit is externally set by an external 1/4 W resistor connected from R_{SC} pin and GND. The value of the resistor must be chosen according to the following formula:

Equation 1:

 I_{sc} (A) = 5/R_{SC} (kohm) with 5 < R_{SC} < 30 (kohm).

Concerning R_{SC} < 5 (kohm) I_{SC} is limited to I_{SC} = 1.1 A (typical value).

This condition (current limited to the I_{SC} value) lasts for a T_{ON} time interval, that can be set by a capacitor (C_{DON}) connected to the ON DELAY pin according to the following formula:

Equation 2:

 t_{ON} = 1.28 µsec/pF for 50 pF < C_{DON} < 2 nF

After the t_{ON} interval has expired the output power MOSFET switches off for the t_{OFF} time interval:

Equation 3:

 $t_{OFF} = 64 \cdot t_{ON}$.

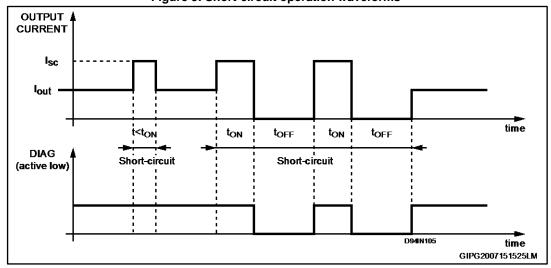


Figure 5: Short-circuit operation waveforms

When the t_{OFF} interval has expired, the output power MOSFET switches on. In this manner two conditions may occur:

- the overload is still present. In this case, the output power MOSFET is again driven to linear mode (limiting the output current to I_{SC}) for another t_{ON}, starting a new cycle
- the overload condition is removed, and the output power MOSFET is no longer driven to linear mode

Please, see the DIAG pin (see *Figure 5: "Short-circuit operation waveforms"*). This unique feature is called short-circuit protection and it ensures a very safe operation even in permanent overload conditions. Note that, the choice of the most appropriate value for the t_{ON} interval (the value of the C_{DON} capacitor), a delay (the t_{ON} itself) prevents a misleading short-circuit information is presented on the DIAG output, when capacitive loads are driven



DocID1637 Rev 5

11/19

or incandescent lamp (a cold filament has a very low resistive value). The non-dissipative short-circuit protection can be disabled (keeping $t_{\text{ON}}=0$ but with the output current still limited to I_{SC} , and diagnostic disabled) simply shorting to ground the ON DELAY pin.

5 Demagnetization of inductive loads

The L6377 has an internal clamping Zener diode, which demagnetises inductive loads. Note that the limitation comes from the peak power that the package can handle. Attention must be paid to a proper thermal design of the board. If load current or inductive value are too big, the peak power dissipation is too high, an external Zener plus diode can perform a demagnetisation versus ground or versus V_s (see *Figure 5: "Short-circuit operation waveforms"* and *Figure 6: "Input comparator hysteresis"*). The breakdown voltage of the external Zener diode must be chosen considering the internal clamping voltage (V_{cl}) and the supply voltage (V_s) according to:

Equation 4:

 $V_z < V_{cl(min.)}$ - $V_{s(max.)}$

for demagnetisation versus ground or

Equation 5:

 $V_{s(max.)} < V_z < V_{cl(min.)}$

for demagnetisation versus V_s.

Figure 6: Input comparator hysteresis

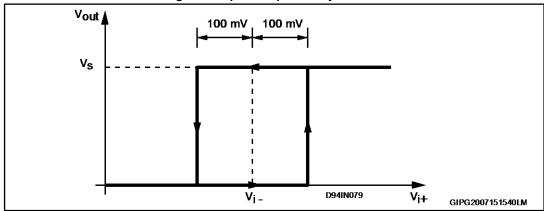
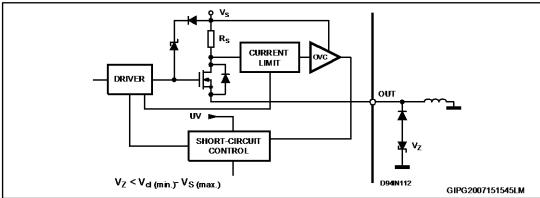


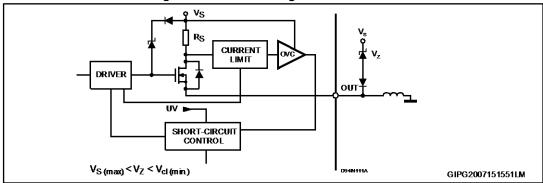
Figure 7: External demagnetisation circuit (versus ground)



57/

DocID1637 Rev 5

Figure 8: External demagnetisation circuit



57

L6377 Package information

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

6.1 SO-14L package information

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Figure 9: SO-14L package outline

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Table 6: SO-14L package mechanical data

Table 0. 90 142 package mechanical data					
Dim.					
Dilli.	Min.	Тур.	Max.		
A	1.35		1.75		
A1	0.10		0.25		
A2	1.10	3.30	1.65		
В	0.19		0.25		
С	1.14	1.52	1.78		
D	8.55		8.75		
E	3.80		4.00		
е		1.27			
Н	5.80		6.20		
h	0.25		0.50		
L	0.40		1.27		
k	0	-	8		
ddd			0.10		



Dimension D doesn't include mold flash, protrusions or gate burrs, which do not exceed $0.15\ mm$ per side.

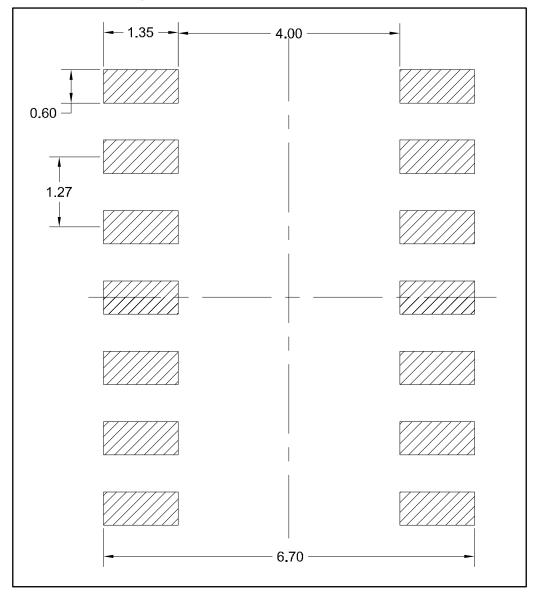


Drawing dimensions include single and matrix versions.



L6377 Package information

Figure 10: SO-14L recommended footprint outline



Revision history L6377

7 Revision history

Table 7: Document revision history

Date	Revision	Changes
17-Aug-2001	1	Initial release.
19-Apr-2005	2	Changed style sheet
22-Jun-2007	3	Changed style sheet
25-Feb-2008	4	Removed obsolete package DIP-14
24-Jul-2015	5	Updated $I_{\mbox{\scriptsize RESET}}$ and $V_{\mbox{\scriptsize RESET}}$ parameter in the table of maximum ratings.

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